OPTOELECTRONICS Infrared Emitters

830 nm, 850 nm, and 870 nm High Intensity and High Optical Power Infrared Emitters



KEY FEATURES

- Radiant intensity up to 600 mW/sr at 100 mA
- Broad option of viewing angles from $\pm 3^{\circ}$ to $\pm 60^{\circ}$
- Up to 5x longer life than competing devices
- Six different packages
- 850 nm based on Light Up[®] surface emitting technology)

BENEFITS

- Reduce the number of emitters required to produce equivalent optical power longer range and better resolution
- Extremely fast switching times for high-speed applications
- 4x the radiant intensity of competing devices. Continuous or pulsed current source

APPLICATIONS

- Illumination for closed circuit TV (night vision) and CMOS image sensors •
- Wireless audio transmission in concert halls, museums, and home theatre surround sound systems
- Emergency response remote control of traffic lights
- Emitter for 3DTV active glasses synchronization
- Automotive illumination for heads up display and back up camera

RESOURCES

- Datasheets: http://www.vishay.com/ir-emitting-diodes/
- Optoelectronis Portfolio: http://www.vishay.com/optoelectronics/
- For technical questions, contact emittertechsupport@vishay.com

Emitters with Radient Intensity up to 600 m/W/sr at 100 mA

VISHAY

Optoelectronics-IR

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VMN-PT0211-1311

One of the World's Largest Manufacturers of

Discrete Semiconductors and Passive Components



PRODUCT SHEET



OPTOELECTRONICS Infrared Emitters

FARTHER WITH FEWER

Reduce the number of infrared emitters by up to half while achieving the same resolution and range by using Vishay's infrared emitters for night time illumination in closed circuit television (CCTV), security camera, and CMOS image sensor applications. For data transmission in museums, concert halls, and other public venues these emitters feature switching times from 10 to 20 ns, meeting the requirements for high-modulation operation and supporting data transmission rates of up to 16 Mbit/sec.

MINIMIZE DEGRADATION

Applications rely on the emitter to maintain performance over time. Designers can not afford to use an emitter that rapidly degrades. Vishay has the lowest degradation when tested against the other leading infrared emitters. The lowest degradation means the best emitters, the longest life.

	Angle	Intensity (mW/sr)			
PART NUMBER	of Half Intensity (°)	0 hours	4000 hours	Degradation (%)	
Vishay TSHG5210	± 10	230	225	2 %	
Vishay TSHG5410	± 18	80	79	2 %	
Competitor A	± 8	171	145	15 %	
Competitor B	± 12	107	96	10 %	
Competitor C	± 10	130	98	25 %	













Little Star





Gullwing



0805

PORTFOLIO

PEAK WAVELENGTH (nm)	PART NUMBER	PACKAGE	RADIANT INTENSITY ¹ (mW/sr)	ANGLE OF HALF INTENSITY (°)	RISE, FALL TIME (ns)
830	<u>TSHG5510</u>	5 mm (T1¾)	32	± 38	15
	<u>TSHG8200</u>	5 mm (T1¾)	180	± 10	20
	<u>TSHG8400</u>	5 mm (T1¾)	70	± 22	20
	<u>VSMG2720</u>	PLCC2	14	± 60	15
850	TSHG5210	5 mm (T1¾)	230	± 10	20
	<u>TSHG5410</u>	5 mm (T1¾)	90	± 18	20
	<u>TSHG6400</u>	5 mm (T1¾)	70	± 22	20
	<u>VSLY5850</u>	5 mm (T1¾)	600	± 3	10
	<u>VSMY1850</u>	0805	12	± 60	10
	<u>VSMY2850G</u>	Gullwing	100	± 10	10
	<u>VSMY2850RG</u>	Reverse Gullwing	100	± 10	10
	<u>VSMY3850</u>	PLCC2	17	± 60	15
	<u>VSMY7850X01</u>	Little Star	170 ²	± 60	15
	VSMY7852X01	Little Star	42 ³	± 60	15
870	<u>TSFF5210</u>	5 mm (T1¾)	180	± 10	15
	<u>TSFF5410</u>	5 mm (T1¾)	70	± 22	
	TSFF5510	5 mm (T1¾)	32	± 38	
	<u>VSMF4720</u>	PLCC2	16	± 60	

¹I_F=100 mA , ²I_F=1 A, ³I_F=250 mA

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